

Features

- 24.7 dB Gain at 100 MHz
- 23.5 dBm P1dB at 100 MHz
- 41 dBm Output IP3 at 100 MHz
- MTTF > 100 Years
- Single Supply

Description

The ASW350, a power amplifier MMIC, has a high linearity, high gain, and high efficiency over a wide range of frequency, being suitable for use in both receiver and transmitter of telecommunication systems up to 4 GHz. The amplifier is available in an SOT-89 package and passes through the stringent DC, RF, and reliability tests.



Package Style: SOT-89

Typical Performance

| Parameters | Units | Typical | |
|----------------|-------|------------------|------------------|
| Frequency | MHz | 100 | 250 |
| Gain | dB | 24.7 | 23 |
| S11 | dB | -15 | -15 |
| S22 | dB | -18 | -14.5 |
| Output IP3 | dBm | 41 ¹⁾ | 40 ²⁾ |
| Noise Figure | dB | 8.0 | 7.1 |
| Output P1dB | dBm | 23.5 | 23 |
| Current | mA | 150 | 150 |
| Device Voltage | V | 5 | 5 |

1) OIP3 is measured with two tones at an output power of +10 dBm/tone separated by 1 MHz.

2) OIP3 is measured with two tones at an output power of +7 dBm/tone separated by 1 MHz.

Product Specifications

| Parameters | Units | Min | Typ | Max |
|-------------------|-------|-----|------|-----|
| Testing Frequency | MHz | | 100 | |
| Gain | dB | 23 | 24.7 | |
| S11 | dB | | -15 | |
| S22 | dB | | -18 | |
| Output IP3 | dBm | 39 | 41 | |
| Noise Figure | dB | | 8.0 | 8.3 |
| Output P1dB | dBm | 22 | 23.5 | |
| Current | mA | 135 | 150 | 165 |
| Device Voltage | V | | 5 | |

Absolute Maximum Ratings

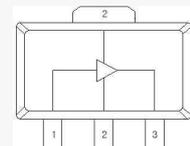
| Parameters | Rating |
|-------------------------------------|---------------|
| Operating Case Temperature | -40 to +85°C |
| Storage Temperature | -40 to +150°C |
| Device Voltage | +6 V |
| Operating Junction Temperature | +150°C |
| Input RF Power (CW, 50ohm matched)* | 25 dBm |

* Please find the max. input power data from http://www.asb.co.kr/pdf/Maximum_Input_Power_Analysis.pdf

Application Circuit

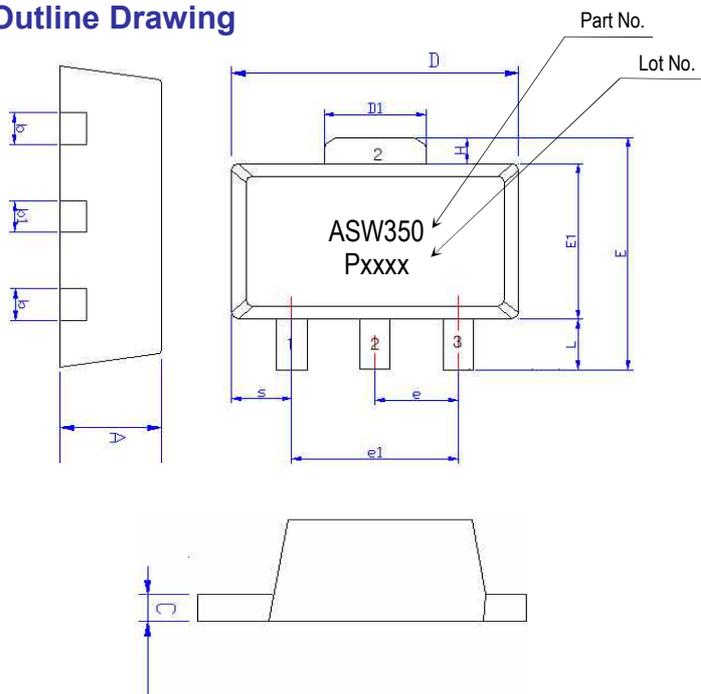
- IF
- 250 MHz

Pin Configuration



| Pin No. | Function |
|---------|---------------|
| 1 | RF IN |
| 2 | GND |
| 3 | RF OUT / Bias |

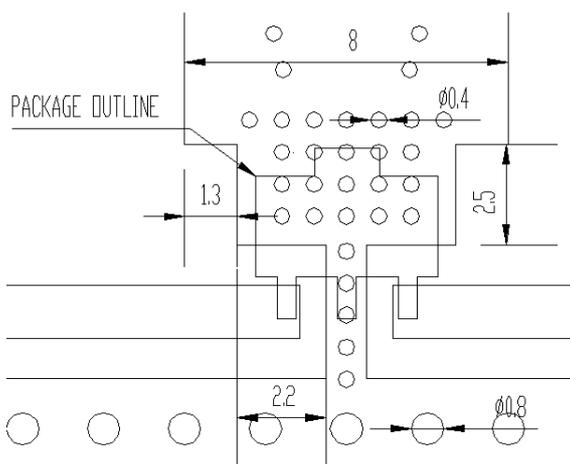
Outline Drawing



| Symbols | Dimensions (In mm) | | |
|---------|--------------------|------|------|
| | MIN | NOM | MAX |
| A | 1.40 | 1.50 | 1.60 |
| L | 0.89 | 1.04 | 1.20 |
| b | 0.36 | 0.42 | 0.48 |
| b1 | 0.41 | 0.47 | 0.53 |
| C | 0.38 | 0.40 | 0.43 |
| D | 4.40 | 4.50 | 4.60 |
| D1 | 1.40 | 1.60 | 1.75 |
| E | 3.64 | --- | 4.25 |
| E1 | 2.40 | 2.50 | 2.60 |
| e1 | 2.90 | 3.00 | 3.10 |
| H | 0.35 | 0.40 | 0.45 |
| S | 0.65 | 0.75 | 0.85 |
| e | 1.40 | 1.50 | 1.60 |

| Pin No. | Function |
|---------|---------------|
| 1 | RF IN |
| 2 | GND |
| 3 | RF OUT / Bias |

Mounting Recommendation (in mm)



- Note:**
1. The number and size of ground via holes in a circuit board is critical for thermal and RF grounding considerations.
 2. We recommend that the ground via holes be placed on the bottom of the lead pin 2 and exposed pad of the device for better RF and thermal performance, as shown in the drawing at the left side.

Ordering Information

| Part Number | Description |
|-------------|-------------|
|-------------|-------------|

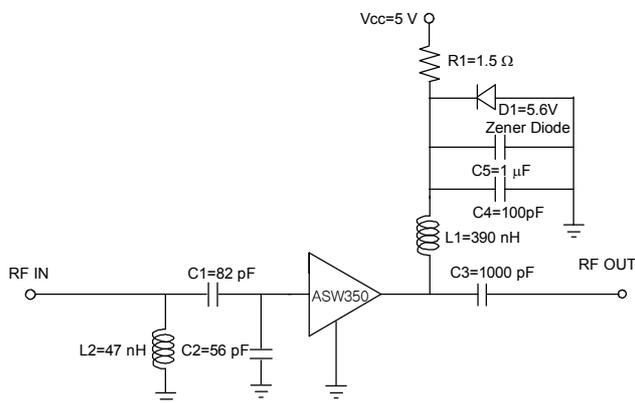
APPLICATION CIRCUIT

IF
 80 ~ 120 MHz
 +5 V

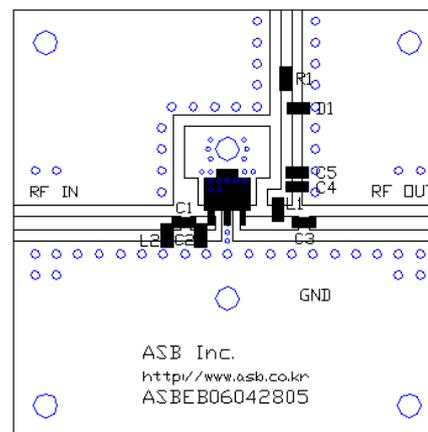
| Frequency (MHz) | 80 | 120 |
|--------------------------------|------|------|
| Magnitude S21 (dB) | 24.5 | 24.3 |
| Magnitude S11 (dB) | -13 | -11 |
| Magnitude S22 (dB) | -18 | -16 |
| Output P1dB (dBm) | 23.5 | |
| Output IP3 ¹⁾ (dBm) | 41 | |
| Noise Figure (dB) | 8.0 | |
| Device Voltage (V) | 5 | |
| Current (mA) | 150 | |

1) OIP3 is measured with two tones at an output power of +10 dBm/tone separated by 1 MHz.

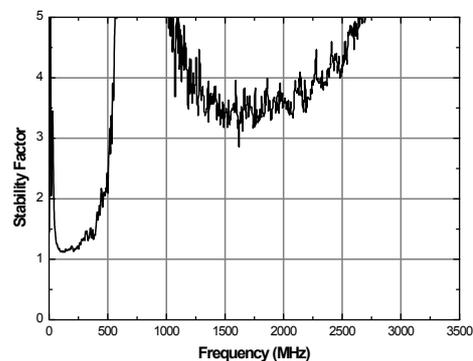
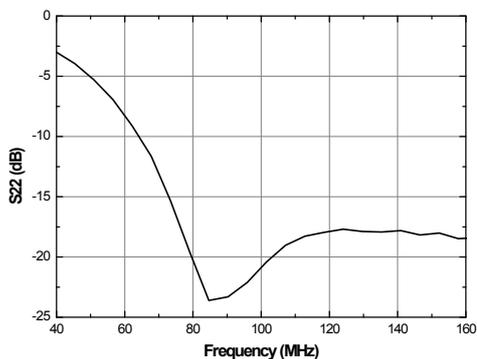
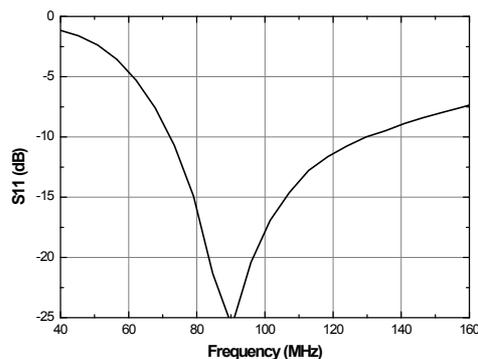
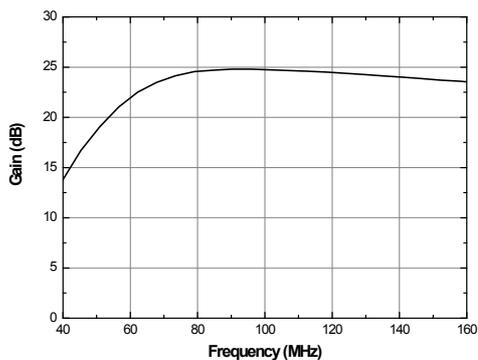
Schematic



Board Layout (FR4, 40x40 mm², 0.8T)



S-parameters & K-factor



APPLICATION CIRCUIT

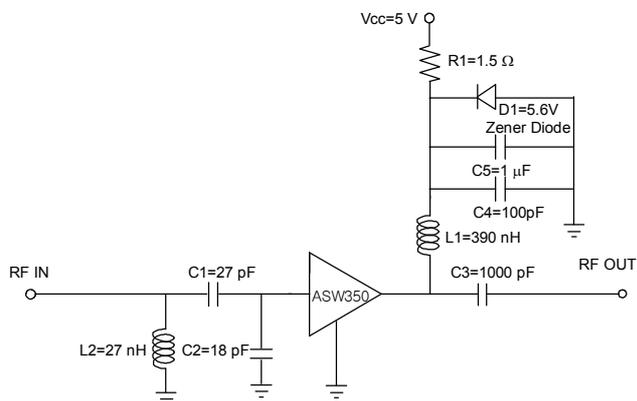
250 MHz

+5 V

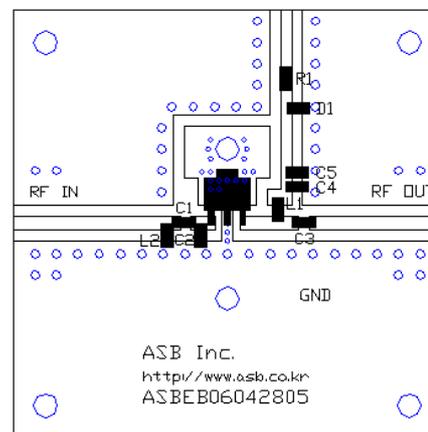
| Frequency (MHz) | 250 |
|--------------------------------|-------|
| Magnitude S21 (dB) | 23 |
| Magnitude S11 (dB) | -15 |
| Magnitude S22 (dB) | -14.5 |
| Output P1dB (dBm) | 23 |
| Output IP3 ¹⁾ (dBm) | 40 |
| Noise Figure (dB) | 7.1 |
| Device Voltage (V) | 5 |
| Current (mA) | 150 |

1) OIP3 is measured with two tones at an output power of +7 dBm/tone separated by 1 MHz.

Schematic



Board Layout (FR4, 40x40 mm², 0.8T)



S-parameters & K-factor

